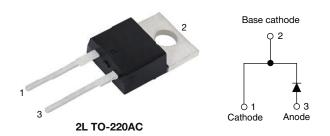
FREE

Vishay Semiconductors

www.vishay.com

Hyperfast Rectifier, 15 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | |
|--|-------------|--|--|--|--|
| I _{F(AV)} | 15 A | | | | |
| V _R | 1200 V | | | | |
| V _F at I _F at 125 °C | 2.1 V | | | | |
| t _{rr} | 29 ns | | | | |
| T _J max. | 175 °C | | | | |
| Package | 2L TO-220AC | | | | |
| Circuit configuration | Single | | | | |

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching RoHS
 losses trade off
 HALOGEN
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: 2L TO-220AC

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Polarity: as per marking device details

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|-----------------------------------|--|-------------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Repetitive peak reverse voltage | V _{RRM} | | 1200 | V | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 98 °C, D = 0.50 | 15 | | | | |
| Repetitive peak forward current | I _{FRM} | T _C = 98 °C, D = 0.50, f = 20 kHz | 30 | A | | | |
| Non-repetitive peak surge current | I _{FSM} | T_{C} = 45 °C, t_{p} = 10 ms, sine wave | 110 | | | | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified) | | | | | | | | |
|--|-------------------------------------|---|------|------|------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 1200 | - | - | | | |
| Forward voltage | V _F | I _F = 15 A | - | 2.5 | 3.3 | V | | |
| | | I _F = 15 A, T _J = 125 °C | - | 2.1 | - | | | |
| Deverse leekerse eurrent | I _R | $V_{R} = V_{R}$ rated | - | - | 50 | | | |
| Reverse leakage current | | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | - | - | 500 | μA | | |
| Junction capacitance | CT | V _R = 200 V | - | 10 | - | pF | | |
| Series inductance | L _S | Measured to lead 5 mm from package body | - | 8 | - | nH | | |

 Revision: 30-Jul-2020
 1
 Document Number: 96608

 For technical questions within your region: DiodesAsia@vishay.com, DiodesEurope@vishay.com

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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | | | |
|---|------------------|---|--|------|------|-------|----|--|--|
| PARAMETER | SYMBOL | TEST | MIN. | TYP. | MAX. | UNITS | | | |
| | | $I_{\rm F} = 1.0 \rm A, dI_{\rm F}/c$ | dt = 100 A/µs, V _R = 30 V | - | 29 | 44 | ns | | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 96 | - | | | |
| | | T _J = 125 °C | | - | 137 | - | | | |
| Posk receivery current | I | T _J = 25 °C | $I_F = 10 A$ $dI_F/dt = 600 A/\mu s$ $V_R = 400 V$ | - | 11.5 | - | A | | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 16 | - | | | |
| Boyeres resevent shares | 0 | T _J = 25 °C | | - | 375 | - | nC | | |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 900 | - | | | |
| Reverse recovery time | + | T _J = 25 °C | | - | 77.5 | - | ns | | |
| Reverse recovery time | t _{rr} | T _J = 125 °C | | - | 106 | - | | | |
| Pook receivery ourrent | 1 | T _J = 25 °C | I _F = 15 A dI _F /dt = 1000 A/μs V _B = 800 V | - | 21 | - | A | | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 29 | - | | | |
| Devenue and evenue also and | 0 | T _J = 25 °C | | - | 680 | - | | | |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 1600 | - | nC | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|--|-----------------------------------|------------------------|--------------|------|------------|------------------------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| Thermal resistance, junction-to-case | R _{thJC} | | - | - | 1.7 | °C/W | | |
| Weight | | | - | 2.0 | - | g | | |
| Weight | | | - | 0.07 | - | oz. | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C | | |
| Marking device | | Case style 2L TO-220AC | E5TX1512 | | | | | |



VS-E5TX1512-M3

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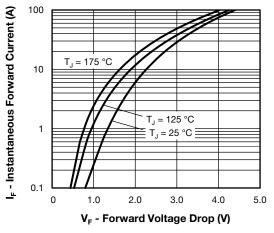


Fig. 1 - Forward Voltage Drop Characteristics

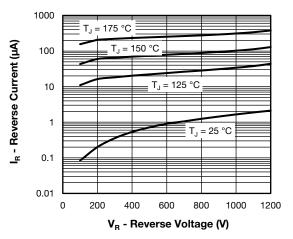


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

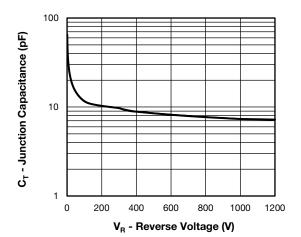


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

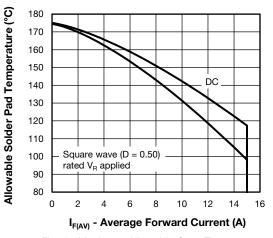


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

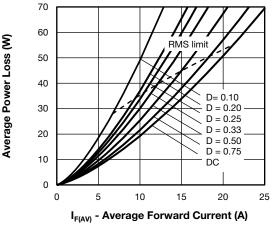


Fig. 5 - Forward Power Loss Characteristics

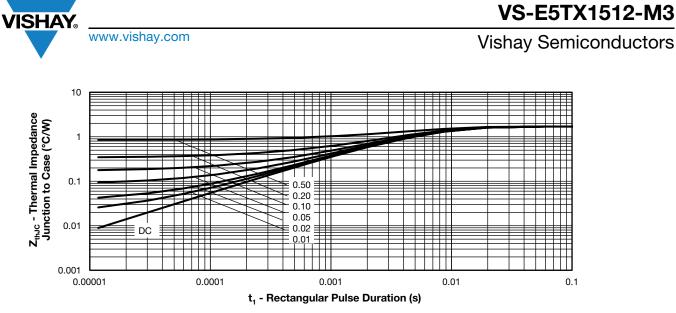
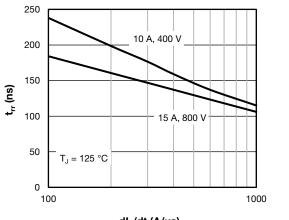


Fig. 6 - Transient Thermal Impedance, Junction to Case



dl_F/dt (Α/μs) Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

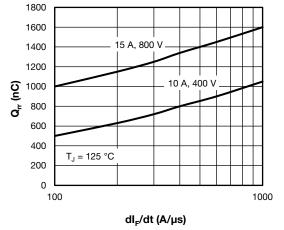


Fig. 8 - Typical Stored Charge vs. dl_F/dt

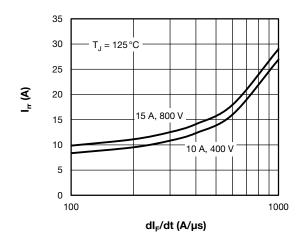
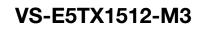


Fig. 9 - Typical Recovery Current vs. dI_F/dt





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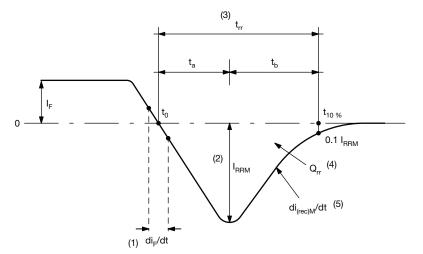


Fig. 10 - Reverse Recovery Waveform and Definitions

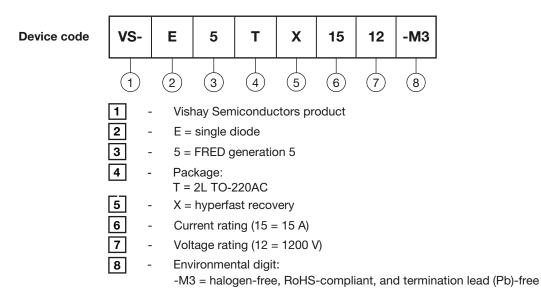
Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10} \%} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|--|--|--|--|--|--|
| Y PER TUBE MINIMUM ORDEI | R QUANTITY PACKAGING DESCRIPTION | | | | | |
| 50 1000 | Antistatic plastic tube | | | | | |
| | Y PER TUBE MINIMUM ORDER 50 1000 | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|---|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?96154 | | | | |
| Part marking information | www.vishay.com/doc?95391 | | | | |
| Revision: 30-Jul-2020 | 5 Document Number: 96608 | | | | |
| For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com | | | | | |

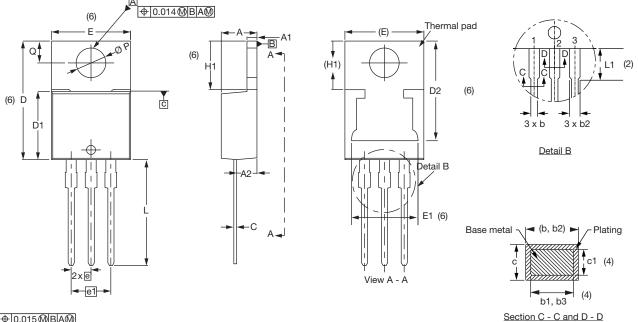
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





| SYMBOL | MILLIN | IETERS | INCHES | | NOTES | |
|---------|--------|--------|--------|-------|-------|--|
| STINDUL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| А | 4.25 | 4.65 | 0.167 | 0.183 | | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | |
| A2 | 2.50 | 2.92 | 0.098 | 0.115 | | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | |
| С | 0.36 | 0.61 | 0.014 | 0.024 | | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | |
| D | 14.85 | 15.35 | 0.585 | 0.604 | 3 | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | | |

| _ | | |
|--------------------------------|---------|-----------------|
| Conforms to JEDEC [®] | outline | TO-220AB |

| SYMBOL | MILLIN | IETERS | INC | NOTES | |
|---------|--------|--------|-------|-------|-------|
| STINDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 11.68 | 13.30 | 0.460 | 0.524 | 6, 7 |
| Ш | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| ØР | 3.54 | 3.91 | 0.139 | 0.154 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| | | | | | |

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

- ⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 13-Jun-2019

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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